

STPS160-Y

Automotive power Schottky rectifier

Datasheet - production data

Features

- Very small conduction losses
- Negligible switching losses
- Low forward voltage drop
- Surface mount miniature packages
- Avalanche capability specified
- ECOPACK[®]2 compliant components
- AEC-Q101 qualified

Description

Single chip Schottky rectifiers suited to switched mode power supplies and high frequency DC to DC converters.

Packaged in SMA and SMB, this device is especially intended for surface mounting and used in low voltage, high frequency inverters, free wheeling and polarity protection for automotive application.

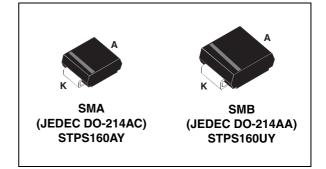


Table 1. Device summary

Symbol	Value
I _{F(AV)}	1 A
V _{RRM}	60 V
T _{j (max)}	150 °C
V _{F (max)}	0.57 V

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This is information on a product in full production.

1 Characteristics

Paramete	Value	Unit			
Repetitive peak reverse voltage	Repetitive peak reverse voltage		V		
Average forward current $T_L = 130 \text{ °C}, \delta = 0.5$		1	Α		
Surge non repetitive forward current	t _p =10 ms sinusoidal	75	А		
The peak reverse current $t_p = 2 \ \mu s \ F = 1 \ kHz \ square$		1	А		
Non repetitive peak reverse current	repetitive peak reverse current $t_p = 100 \ \mu s \ square$		Α		
Repetitive peak avalanche power $t_p = 1 \ \mu s \ T_j = 25 \ ^{\circ}C$		2400	W		
Storage temperature range	-65 to + 150	°C			
Operating junction temperature range	-40 to + 150	°C			
Critical rate of rise of reverse voltage	10000	V/µs			
	Repetitive peak reverse voltage Average forward current Surge non repetitive forward current Repetitive peak reverse current Non repetitive peak reverse current Repetitive peak avalanche power Storage temperature range Operating junction temperature range	Average forward current $T_L = 130 \ ^{\circ}C, \delta = 0.5$ Surge non repetitive forward current $t_p = 10 \ ms \ sinusoidal$ Repetitive peak reverse current $t_p = 2 \ \mu s \ F = 1 \ kHz \ square$ Non repetitive peak reverse current $t_p = 100 \ \mu s \ square$ Repetitive peak avalanche power $t_p = 1 \ \mu s \ T_j = 25 \ ^{\circ}C$ Storage temperature rangeOperating junction temperature range	Repetitive peak reverse voltage60Average forward current $T_L = 130 ^{\circ}\text{C}, \delta = 0.5$ 1Surge non repetitive forward current $t_p = 10 \text{ms sinusoidal}$ 75Repetitive peak reverse current $t_p = 2 \mu \text{s} \text{F} = 1 \text{kHz square}$ 1Non repetitive peak reverse current $t_p = 100 \mu \text{s square}$ 1Repetitive peak avalanche power $t_p = 1 \mu \text{s} T_j = 25 ^{\circ}\text{C}$ 2400Storage temperature range-65 to + 150-40 to + 150		

Table 2. Absolute ratings (limiting values)

1. $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3.Thermal resistance

Symbol	Parameter		Value	Unit
Р	lupation to load	SMA	30	°C/W
R _{th(j-l)}	Junction to lead	SMB	23	C/VV

Table 4.Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾ Reverse le	Povorco lookago ourront	T _j = 25 °C	$V_{R} = V_{RRM}$			4	μA
'R` ′	I _R ⁽¹⁾ Reverse leakage current	T _j = 125 °C			1.1	4	mA
	V _F ⁽²⁾ Forward voltage drop	T _j = 25 °C	I _F = 1 A			0.67	
V (2)		T _j = 125 °C			0.49	0.57	V
VF`'		T _j = 25 °C	I _F = 2 A			0.8	v
		T _j = 125 °C			0.58	0.65	

1. Pulse test: tp = 5 ms, δ < 2%

2. Pulse test: tp = 380 $\mu s, \, \delta < 2\%$

To evaluate the conduction losses use the following equation:

 $P = 0.49 \text{ x } I_{F(AV)} + 0.08 \text{ } I_{F}^{2}_{(RMS)}$



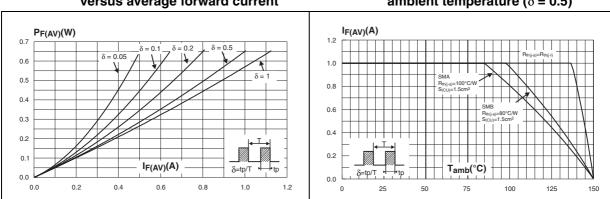
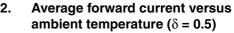


Figure 1. Average forward power dissipation Figure 2. versus average forward current



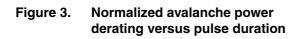


Figure 4. Normalized avalanche power derating versus junction temperature

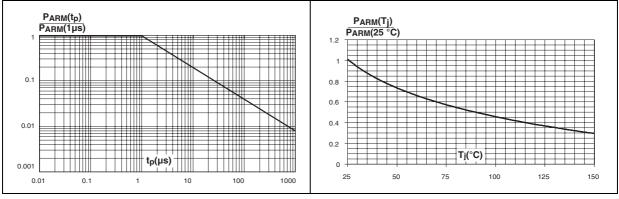
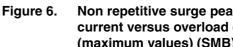


Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values) (SMA)



Non repetitive surge peak forward current versus overload duration (maximum values) (SMB)

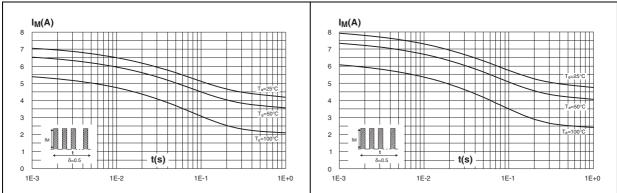
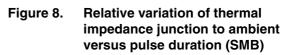
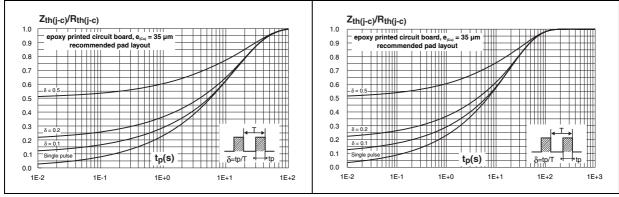
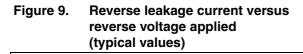
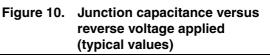


Figure 7. Relative variation of thermal impedance junction to ambient versus pulse duration (SMA)









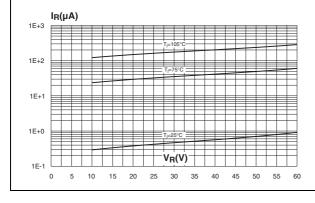


Figure 11. Forward voltage drop versus forward current (maximum values)

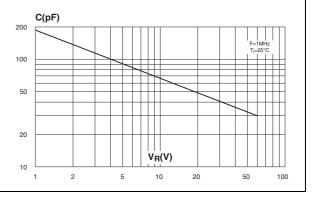
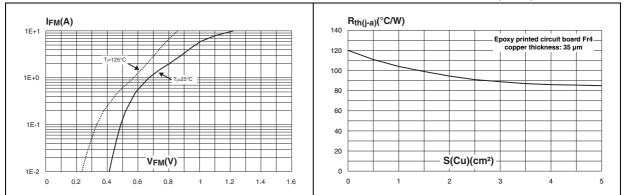
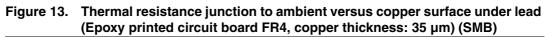
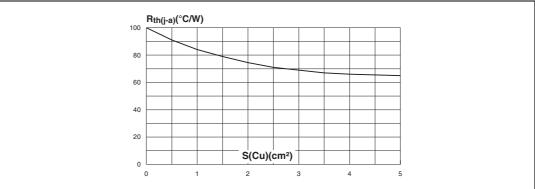


Figure 12. Thermal resistance junction to ambient versus copper surface under each lead (SMA)











2 Package information

- Epoxy meets UL94, V0
- Band indicates cathode

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK[®] is an ST trademark.

Table 5. SMA dimensions

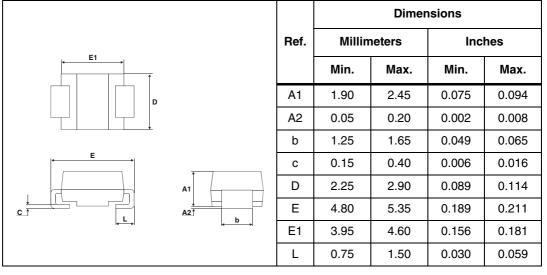
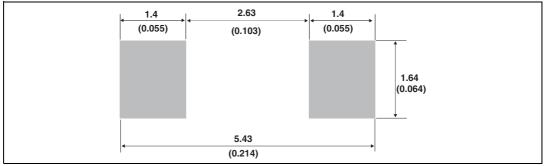


Figure 14. Footprint, dimensions in mm (inches)

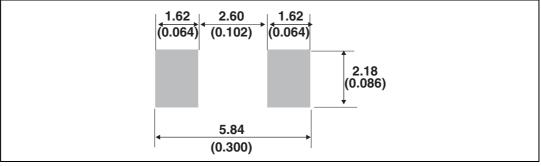




	uniensions					
			Dimensions			
E1	F1		Millimeters		Inches	
			Min.	Max.	Min.	Max.
	A1	1.90	2.45	0.075	0.096	
		A2	0.05	0.20	0.002	0.008
	b	1.95	2.20	0.077	0.087	
	С	0.15	0.40	0.006	0.016	
		D	3.30	3.95	0.130	0.156
		Е	5.10	5.60	0.201	0.220
	le_≱l le b	E1	4.05	4.60	0.159	0.181
		L	0.75	1.50	0.030	0.059

Table 6.SMB dimensions







3 Ordering information

Table 7.Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS160AY	GA6Y	SMA	0.068 g	5000	Tape and reel
STPS160UY	E16Y	SMB	0.107 g	2500	Tape and reel

4 Revision history

Table 8.Document revision history

Date	Revision	Changes
28-Jun-2012	1	Initial release.

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